NSN 5962-01-484-6535

Memory Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Aircraft, awacs, e-3a
Features Provided:
Monolithic and electrostatic sensitive and programmed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Product Name:
Microcircuit, programmed
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 6.0 volts input
Time Rating Per Chacteristic:
120.00 nanoseconds af output megawatts
Memory Device Type:
Eeprom
Special Features:
Altered item/uses smd 5962-3826707mxx
Test Data Document:
$96906 \hbox{-mil-std-}883 \ standard \ (includes \ industry \ or \ association \ standards, \ individual \ manufactureer \ standards, \ etc.).$
Terminal Type And Quantity:
32 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:
No
Fiig:
A458a0